

D40K SERIES

**NPN SILICON
DARLINGTON POWER
TRANSISTOR**



TO-202 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR D40K series types are NPN silicon Darlington power transistors designed for general purpose amplifier applications where high gain is required.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^{\circ}\text{C}$)

Collector-Emitter Voltage	
Collector-Emitter Voltage	
Emitter-Base Voltage	
Continuous Collector Current	
Peak Collector Current	
Continuous Base Current	
Power Dissipation	
Power Dissipation ($T_C=25^{\circ}\text{C}$)	
Operating and Storage Junction Temperature	
Thermal Resistance	
Thermal Resistance	

SYMBOL	D40K1, 3	D40K2, 4	UNITS
V_{CES}	30	50	V
V_{CEO}	30	50	V
V_{EBO}		13	V
I_C		2.0	A
I_{CM}		3.0	A
I_B		0.2	A
P_D		1.67	W
P_D		10	W
T_J, T_{stg}	-65 to +150		$^{\circ}\text{C}$
θ_{JA}	75		$^{\circ}\text{C/W}$
θ_{JC}	12.5		$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_C=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CES}	$V_{CE}=\text{Rated } V_{CES}$			500	nA
I_{EBO}	$V_{EB}=13\text{V}$			100	nA
BV_{CEO}	$I_C=10\text{mA}$ (D40K1, 3)	30			V
BV_{CEO}	$I_C=10\text{mA}$ (D40K2, 4)	50			V
$V_{CE(\text{SAT})}$	$I_C=1.5\text{A}, I_B=3.0\text{mA}$ (D40K1, 2)			1.5	V
$V_{CE(\text{SAT})}$	$I_C=1.0\text{A}, I_B=2.0\text{mA}$ (D40K3, 4)			1.5	V
$V_{BE(\text{SAT})}$	$I_C=1.5\text{A}, I_B=3.0\text{mA}$ (D40K1, 2)			2.5	V
$V_{BE(\text{SAT})}$	$I_C=1.0\text{A}, I_B=2.0\text{mA}$ (D40K3, 4)			2.5	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=200\text{mA}$	10K			
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.5\text{A}$ (D40K1, 2)	1K			
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$ (D40K3, 4)	1K			
f_T	$V_{CE}=5.0\text{V}, I_C=20\text{mA}$		75		MHz
C_{cb}	$V_{CB}=10\text{V}, f=1.0\text{MHz}$			10	pF

R1 (23-January 2012)

D40K SERIES

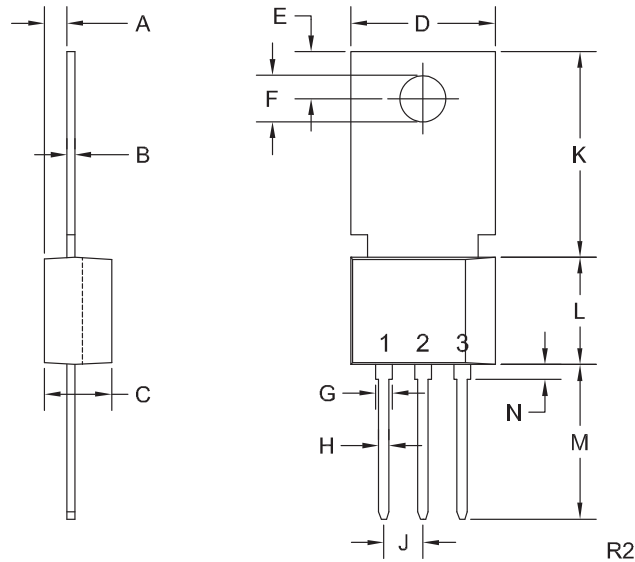
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TO-202 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector
- Tab is common to pin 3

MARKING:

FULL PART NUMBER

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.071	1.40	1.80
B	0.016	0.024	0.40	0.60
C	0.173	0.181	4.40	4.60
D	0.374	0.413	9.50	10.5
E	0.118	0.154	3.00	3.90
F (DIA)	0.124	0.150	3.15	3.80
G	0.035	0.055	0.90	1.40
H	0.023	0.031	0.59	0.80
J	0.094	0.106	2.39	2.69
K	0.459	0.559	11.66	14.21
L	0.280	0.346	7.12	8.80
M	0.406	0.531	10.3	13.5
N	0.024	0.059	0.60	1.50

TO-202 (REV: R2)

R1 (23-January 2012)